SN74LVC8T245 8-BIT DUAL-SUPPLY BUS TRANSCEIVER

WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

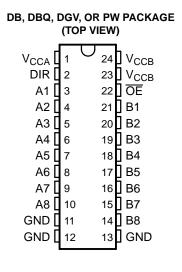
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## FEATURES

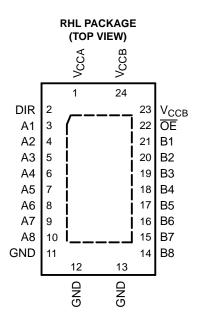
**RUMENTS** 

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- Control Inputs V<sub>IH</sub>/V<sub>IL</sub> Levels Are Referenced to V<sub>CCA</sub> Voltage
- V<sub>CC</sub> Isolation Feature If Either V<sub>CC</sub> Input Is at GND, All Are in the High-Impedance State
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.65-V to 5.5-V Power-Supply Range



- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 4000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



## **DESCRIPTION/ORDERING INFORMATION**

This 8-bit noninverting bus transceiver uses two separate configurable power-supply rails. The SN74LVC8T245 is optimized to operate with  $V_{CCA}$  and  $V_{CCB}$  set at 1.65 V to 5.5 V. The A port is designed to track  $V_{CCA}$ .  $V_{CCA}$  accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5.5-V voltage nodes.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE	(1)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RHL	Tape and reel	SN74LVC8T245RHLR	NH245
	SSOP – DBR	Tape and reel	SN74LVC8T245DBR	NH245
40°C to 95°C	SSOP (QSOP) – DBQ	Tape and reel	SN74LVC8T245DBQR	NH245
–40°C to 85°C	TSSOP – PW	Tube	SN74LVC8T245PW	NUD4E
	1550P - PW	Tape and reel	SN74LVC8T245PWR	- NH245
	TVSOP – DGV	Tape and reel	SN74LVC8T245DGVR	NH245

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

The SN74LVC8T245 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (OE) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I<sub>CC</sub> and I<sub>CCZ</sub>.

The SN74LVC8T245 is designed so that the control pins (DIR and  $\overline{OE}$ ) are supplied by V<sub>CCA</sub>.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V<sub>CC</sub> isolation feature ensures that if either V<sub>CC</sub> input is at GND, all outputs are in the high-impedance state.

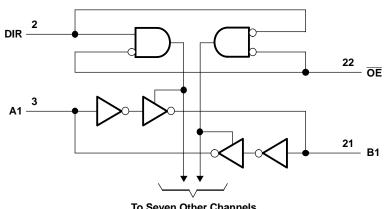
To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

CONTRO	L INPUTS	OUTPUT C	CIRCUITS			
ŌĒ	DIR	A PORT	B PORT OPERATION			
L	L	Enabled	Hi-Z	B data to A bus		
L	Н	Hi-Z	Enabled	A data to B bus		
Н	Х	Hi-Z	Hi-Z	Isolation		

LOGIC DIAGRAM (POSITIVE LOGIC)

#### FUNCTION TABLE<sup>(1)</sup> (EACH 8-BIT SECTION)

(1) Input circuits of the data I/Os are always active.



**To Seven Other Channels** 

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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CCA}$ $V_{CCB}$	Supply voltage range		-0.5	6.5	V
		I/O ports (A port)	-0.5	6.5	
VI	Input voltage range <sup>(2)</sup>	I/O ports (B port)	-0.5	6.5	V
		Control inputs	-0.5	6.5	
V	Voltage range applied to any output	A port	-0.5	6.5	V
Vo	in the high-impedance or power-off state <sup>(2)</sup>	B port	-0.5	6.5	v
V	Voltage range applied to any output in the high or low state $\binom{2}{3}$	A port	-0.5 V	<sub>CCA</sub> + 0.5	V
Vo	Voltage range applied to any output in the high or low state $^{(2)(3)}$	B port	-0.5 V	<sub>ССВ</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through each $V_{CCA}$ , $V_{CCB}$ , and GND			±100	mA
		DB package		63	
		DBQ package		61	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DGV package		86	°C/W
		PW package		88	
		RHL package		43	
T <sub>stg</sub>	Storage temperature range	· · ·	-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. (2)

(3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.
 (4) The package thermal impedance is calculated in accordance with JESD 51-7.

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## Recommended Operating Conditions<sup>(1)(2)(3)(4)</sup>

			V <sub>CCI</sub>	V <sub>cco</sub>	MIN	MAX	UNIT
V <sub>CCA</sub>	O				1.65	5.5	
V <sub>CCB</sub>	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		$V_{CCI}  imes 0.65$		
. ,	High-level	<b>D</b> ( ) (5)	2.3 V to 2.7 V		1.7		
VIH	input voltage	Data inputs <sup>(5)</sup>	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCI}  imes 0.7$		
			1.65 V to 1.95 V			$V_{CCI}  imes 0.35$	
. ,	Low-level		2.3 V to 2.7 V			0.7	
V <sub>IL</sub>	input voltage	Data inputs <sup>(5)</sup>	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCI}  imes 0.3$	
			1.65 V to 1.95 V		$V_{CCA}  imes 0.65$		
. ,	High-level	Control inputs	2.3 V to 2.7 V		1.7		
V <sub>IH</sub>	input voltage	(referenced to V <sub>CCA</sub> ) <sup>(6)</sup>	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCA}  imes 0.7$		
			1.65 V to 1.95 V			$V_{CCA}  imes 0.35$	
. ,	Low-level	Control inputs	2.3 V to 2.7 V			0.7	
V <sub>IL</sub>	input voltage	(referenced to $V_{CCA}$ ) <sup>(6)</sup>	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCA}  imes 0.3$	
VI	Input voltage	Control inputs			0	5.5	V
. /	Input/output	Active state			0	V <sub>CCO</sub>	V
V <sub>I/O</sub>	voltage	3-State			0	5.5	V
		<u>.</u>		1.65 V to 1.95 V		-4	
	Lich lovel output	autrant		2.3 V to 2.7 V		-8	~ ^
I <sub>ОН</sub>	High-level output	current		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
		ourroot		2.3 V to 2.7 V		8	mA
l <sub>OL</sub>	Low-level output	current		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
	Input transition	Data innuta	2.3 V to 2.7 V			20	n=^/
∆t/∆v	rise or fall rate	Data inputs	3 V to 3.6 V			10	ns/V
			4.5 V to 5.5 V			5	
T <sub>A</sub>	Operating free-ai	r temperature			-40	85	°C

(1)  $V_{CCI}$  is the  $V_{CC}$  associated with the data input port. (2)  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

All unused or driven (floating) data inputs (I/Os) of the device must be held at logic HIGH or LOW (preferably V<sub>CCI</sub> or GND) to ensure proper device operation and minimize power. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature (3) number SCBA004.

(4) All unused control inputs must be held at  $V_{CCA}$  or GND to ensure proper device operation and minimize power comsumption. (5) For  $V_{CCI}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCI} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCI} \times 0.3$  V. (6) For  $V_{CCA}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCA} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCA} \times 0.3$  V.

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# Electrical Characteristics<sup>(1)(2)</sup>

over recommended operating free-air temperature range (unless otherwise noted)

PAR	METER	TEST CONDIT	IONS	V <sub>CCA</sub>	V <sub>CCB</sub>	MIN TYP	MAX	MIN	MAX	UNIT	
		I <sub>OH</sub> = −100 μA,	$V_I = V_{IH}$	1.65 V to 4.5 V	1.65 V to 4.5 V			V <sub>CCO</sub> – 0.1			
		I <sub>OH</sub> = -4 mA,	$V_I = V_{IH}$	1.65 V	1.65 V			1.2			
V <sub>OH</sub>		I <sub>OH</sub> = -8 mA,	$V_{I} = V_{IH}$	2.3 V	2.3 V			1.9		V	
		I <sub>OH</sub> = -24 mA,	$V_I = V_{IH}$	3 V	3 V			2.4			
		I <sub>OH</sub> = -32 mA,	$V_I = V_{IH}$	4.5 V	4.5 V			3.8			
		I <sub>OL</sub> = 100 μA,	$V_{I} = V_{IL}$	1.65 V to 4.5 V	1.65 V to 4.5 V				0.1		
		$I_{OL} = 4 \text{ mA},$	$V_{I} = V_{IL}$	1.65 V	1.65 V				0.45		
V <sub>OL</sub>		I <sub>OL</sub> = 8 mA,	$V_{I} = V_{IL}$	2.3 V	2.3 V				0.3	V	
T		I <sub>OL</sub> = 24 mA,	$V_{I} = V_{IL}$	3 V	3 V				0.55		
		I <sub>OL</sub> = 32 mA,	$V_{I} = V_{IL}$	4.5 V	4.5 V				0.55		
I <sub>I</sub>	DIR	$V_I = V_{CCA}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V		±1		±2	μΑ	
	A or B		,	0 V	0 to 5.5 V		±1		±2 A		
off	port	$V_{\rm I}$ or $V_{\rm O} = 0$ to 5.5 V	/	0 to 5.5 V	0 V		±1		±2	μA	
l <sub>oz</sub>	A or B port	$\frac{V_{O}}{OE} = V_{CCO} \text{ or GND},$ $\frac{V_{O}}{OE} = V_{IH}$		1.65 V to 5.5 V	1.65 V to 5.5 V		±1		±2	μΑ	
ŀ				1.65 V to 5.5 V	1.65 V to 5.5 V				15		
CCA		$V_{I} = V_{CCI} \text{ or } GND,  I_{O} = 0$		5 V	0 V				15	μA	
				0 V	5 V				-2		
				1.65 V to 5.5 V	1.65 V to 5.5 V				15		
I <sub>ССВ</sub>		$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	5 V	0 V				-2	μA	
				0 V	5 V				15		
I <sub>CCA</sub> +	I <sub>CCB</sub>	$V_I = V_{CCI}$ or GND,	$I_{O} = 0$	1.65 V to 5.5 V	1.65 V to 5.5 V				25	μA	
	A port	One A port at $V_{CCA}$ DIR at $V_{CCA}$ , B port	– 0.6 V, = open						50		
∆I <sub>CCA</sub>	DIR	DIR at $V_{CCA} - 0.6 V$ , B port = open, A port at $V_{CCA}$ or GND		3 V to 5.5 V	3 V to 5.5 V				50	μA	
$\Delta I_{CCB}$	B port	One B port at V <sub>CCB</sub> DIR at GND, A port		3 V to 5.5 V	3 V to 5.5 V				50	μA	
C <sub>i</sub>	Control inputs	$V_{I} = V_{CCA} \text{ or } GND$		3.3 V	3.3 V	2	1		5	pF	
C <sub>io</sub>	A or B port	$V_{O} = V_{CCA/B}$ or GNE	)	3.3 V	3.3 V	8.8	5		10	pF	

 $\begin{array}{ll} \mbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \mbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \end{array}$ 



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#### **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CCA}$  = 1.8 V ± 0.15 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>ССВ</sub> = ± 0.1		V <sub>ССВ</sub> = ± 0.2		V <sub>ССВ</sub> = ± 0.	= 3.3 V 3 V	$V_{CCB}$ = 5 V ± 0.5 V		UNIT
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A	В	1.7	21.9	1.3	9.2	1	7.4	0.8	7.1	ns
t <sub>PHL</sub>	~	В	1.7	21.9	1.5	9.2		7.4	0.0	7.1	115
t <sub>PLH</sub>	В	А	0.9	23.8	0.8	23.6	0.7	23.4	0.7	23.4	ns
t <sub>PHL</sub>	В	~	0.3	23.0	0.0	23.0	0.7	20.4	0.7	23.4	115
t <sub>PHZ</sub>	OE	A	1.5	29.6	1.5	29.4	1.5	29.3	1.4	29.2	ns
t <sub>PLZ</sub>	OL	Α.	1.5	29.0	1.5	29.4	1.5	29.5	1.4	29.2	115
t <sub>PHZ</sub>	OE	В	2.4	32.2	1.9	13.1	1.7	12	1.3	10.3	ns
t <sub>PLZ</sub>	OL	D	2.4	JZ.Z	1.9	13.1	1.7	12	1.5	10.5	115
t <sub>PZH</sub>	OE	А	0.4	24	0.4	23.8	0.4	23.7	0.4	23.7	ns
t <sub>PZL</sub>	UL	Α.	0.4	24	0.4	23.0	0.4	23.1	0.4	23.1	115
t <sub>PZH</sub>	OE	В	1.8	32	1.5	16	1.2	12.6	0.9	10.8	ns
t <sub>PZL</sub>	UE	D	1.0	32	1.5	10	1.2	12.0	0.9	10.0	115

#### **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CCA}$  = 2.5 V ± 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTBUT)	V <sub>CCB</sub> = ± 0.1		V <sub>ССВ</sub> = ± 0.2		V <sub>ССВ</sub> = ± 0.		V <sub>ССВ</sub> ± 0.		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A	В	1.5	21.4	1.2	9	0.8	6.2	0.6	4.8	ns
t <sub>PHL</sub>	A	D	1.5	21.4	1.2	9	0.0	0.2	0.0	4.0	115
t <sub>PLH</sub>	В	B A		9.3	1	9.1	1	8.9	0.9	8.8	ns
t <sub>PHL</sub>	6	~	1.2	5.5	1	3.1	ļ	0.3	0.9	0.0	115
t <sub>PHZ</sub>	ŌĒ	A	1.4	9	1.4	9	1.4	9	1.4	9	ns
t <sub>PLZ</sub>	UL	~	1.4	5	1.4	3	1.4	3	1.4	3	115
t <sub>PHZ</sub>	OE	В	2.3	29.6	1.8	11	1.7	9.3	0.9	6.9	ns
t <sub>PLZ</sub>	UL	D	2.5	23.0	1.0	11	1.7	5.5	0.5	0.3	115
t <sub>PZH</sub>	OE	А	1	10.9	1	10.9	1	10.9	1	10.9	ns
t <sub>PZL</sub>	UL	~	1	10.9	I	10.9	I	10.9	1	10.9	113
t <sub>PZH</sub>	OE	В	1.7	28.2	1.5	12.9	1.2	9.4	1	6.9	ns
t <sub>PZL</sub>	UL	В	1.7	20.2	1.5	12.9	1.2	9.4	I	0.9	115

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### **Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CCA}$  = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub> = ± 0.15		V <sub>CCB</sub> = ± 0.2		V <sub>ССВ</sub> = ± 0.	= 3.3 V 3 V	$V_{CCB}$ = 5 V ± 0.5 V		UNIT	
	(INFOT)	(001201)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t <sub>PLH</sub>	A	В	1.5	21.2	1.1	8.8	0.8	6.3	0.5	4.4	ns	
t <sub>PHL</sub>	~	D	1.5	21.2	1.1	0.0	0.0	0.5	0.5	4.4	115	
t <sub>PLH</sub>	в	А	0.8	7.2	0.8	6.2	0.7	6.1	0.6	6	ns	
t <sub>PHL</sub>	В	~	0.0	1.2	0.0	0.2	0.7	0.1	0.0	0	115	
t <sub>PHZ</sub>	OE	A	1.6	8.2	1.6	8.2	1.6	8.2	1.6	8.2	ns	
t <sub>PLZ</sub>	OL	A	1.0	0.2	1.0	0.2	1.0	0.2	1.0	0.2	115	
t <sub>PHZ</sub>	OE	В	2.1	29	1.7	10.3	1.5	8.6	0.8	6.3	ns	
t <sub>PLZ</sub>	OL	D	2.1	29	1.7	10.5	1.5	0.0	0.0	0.5	115	
t <sub>PZH</sub>	OE	А	0.8	8.1	0.8	8.1	0.8	8.1	0.8	8.1	ns	
t <sub>PZL</sub>	UE	A	0.0	0.1	0.0	0.1	0.0	0.1	0.0	0.1	115	
t <sub>PZH</sub>	OE	В	1.8	27.7	1.4	12.4	1.1	8.5	0.9	6.4	ns	
t <sub>PZL</sub>	UE	D	1.0	21.1	1.4	12.4	1.1	0.5	0.9	0.4	115	

#### **Switching Characteristics**

over recommended operating free-air temperature range, V<sub>CCA</sub> = 5 V  $\pm$  0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = ± 0.1			2.5 V .2 V	V <sub>CC</sub> = ± 0.		$V_{CC} = 5 V \\ \pm 0.5 V$		UNIT
	(INPOT)	(001201)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A	В	1.5	21.4	1	8.8	0.7	6	0.4	4.2	ns
t <sub>PHL</sub>	~	D	1.5	21.4	1	0.0	0.7	0	0.4	4.2	115
t <sub>PLH</sub>	В	А	0.7	7	0.4	4.8	0.3	4.5	0.3	4.3	ns
t <sub>PHL</sub>	В	~	0.7	1	0.4	4.0	0.5	4.5	0.5	4.5	115
t <sub>PHZ</sub>	OE	A	0.3	5.4	0.3	5.4	0.3	5.4	0.3	5.4	ns
t <sub>PLZ</sub>	UE	A	0.5	5.4	0.5	5.4	0.5	5.4	0.5	5.4	115
t <sub>PHZ</sub>	OE	В	2	28.7	1.6	9.7	1.4	8	0.7	5.7	ns
t <sub>PLZ</sub>	UE	Б	2	20.1	1.0	9.7	1.4	0	0.7	5.7	115
t <sub>PZH</sub>	OE	А	0.7	6.4	0.7	6.4	0.7	6.4	0.7	6.4	ns
t <sub>PZL</sub>	UE	A	0.7	0.4	0.7	0.4	0.7	0.4	0.7	0.4	115
t <sub>PZH</sub>	ŌĒ	В	1.5	27.6	1.3	11.4	1	0 1	0.9	6	20
t <sub>PZL</sub>		В	1.5	27.6	1.3	11.4	1	8.1	0.9	0	ns

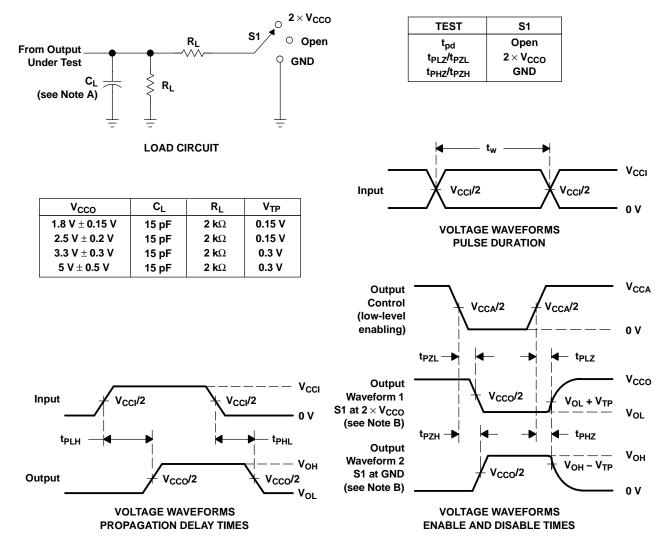
#### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CCA</sub> = V <sub>CCB</sub> = 1.8 V TYP	V <sub>CCA</sub> = V <sub>CCB</sub> = 2.5 V TYP	V <sub>CCA</sub> = V <sub>CCB</sub> = 3.3 V TYP	V <sub>CCA</sub> = V <sub>CCB</sub> = 5 V TYP	UNIT
<b>C</b> (1)	A-port input, B-port output		2	2	2	3	
C <sub>pdA</sub> <sup>(1)</sup>	B-port input, A-port output	$C_L = 0,$	12	13	13	16	~ -
<b>C</b> (1)	A-port input, B-port output	f = 10 MHz, t <sub>r</sub> = t <sub>f</sub> = 1 ns	13	13	14	16	pF
C <sub>pdB</sub> <sup>(1)</sup>	B-port input, A-port output		2	2	2	3	Ţ

(1) Power dissipation capacitance per transceiver

SCES584A-JUNE 2005-REVISED AUGUST 2005



#### PARAMETER MEASUREMENT INFORMATION

Texas

ISTRUMENTS www.ti.com

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , dv/dt  $\geq$  1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PL7}$  and  $t_{PH7}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
- I.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms



24-Jan-2013

### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
74LVC8T245DBQRG4	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LVC8T245	Samples
74LVC8T245RHLRG4	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NH245	Samples
SN74LVC8T245DBQR	ACTIVE	SSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LVC8T245	Samples
SN74LVC8T245DBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245DBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245DBRG4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245DGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC8T245	Samples
SN74LVC8T245DWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC8T245	Samples
SN74LVC8T245NSR	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC8T245	Samples
SN74LVC8T245NSRG4	ACTIVE	SO	NS	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC8T245	Samples
SN74LVC8T245PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245PWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245PWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples



24-Jan-2013

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN74LVC8T245PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NH245	Samples
SN74LVC8T245RHLR	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	NH245	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC8T245 :

Automotive: SN74LVC8T245-Q1

Enhanced Product: SN74LVC8T245-EP

# PACKAGE OPTION ADDENDUM



www.ti.com

24-Jan-2013

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC8T245DBQR	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC8T245DBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74LVC8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC8T245DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74LVC8T245NSR	SO	NS	24	2000	330.0	24.4	8.2	15.4	2.5	12.0	24.0	Q1
SN74LVC8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74LVC8T245RHLR	QFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

26-Jan-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC8T245DBQR	SSOP	DBQ	24	2500	367.0	367.0	38.0
SN74LVC8T245DBR	SSOP	DB	24	2000	367.0	367.0	38.0
SN74LVC8T245DGVR	TVSOP	DGV	24	2000	367.0	367.0	35.0
SN74LVC8T245DWR	SOIC	DW	24	2000	367.0	367.0	45.0
SN74LVC8T245NSR	SO	NS	24	2000	367.0	367.0	45.0
SN74LVC8T245PWR	TSSOP	PW	24	2000	367.0	367.0	38.0
SN74LVC8T245RHLR	QFN	RHL	24	1000	210.0	185.0	35.0

# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



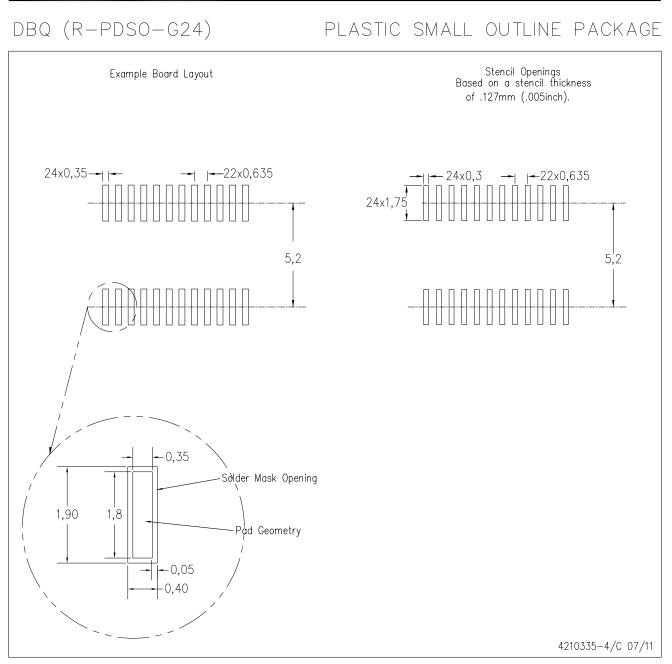
NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.





NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

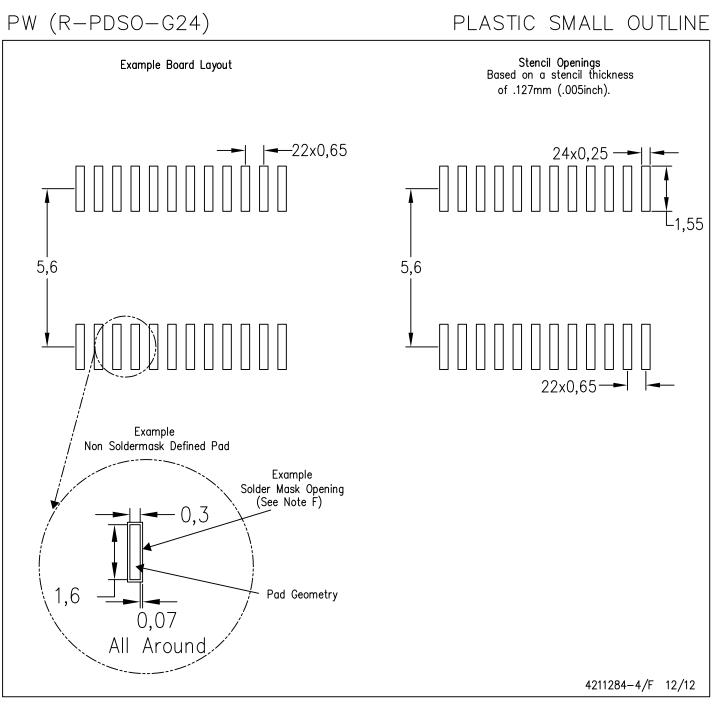
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



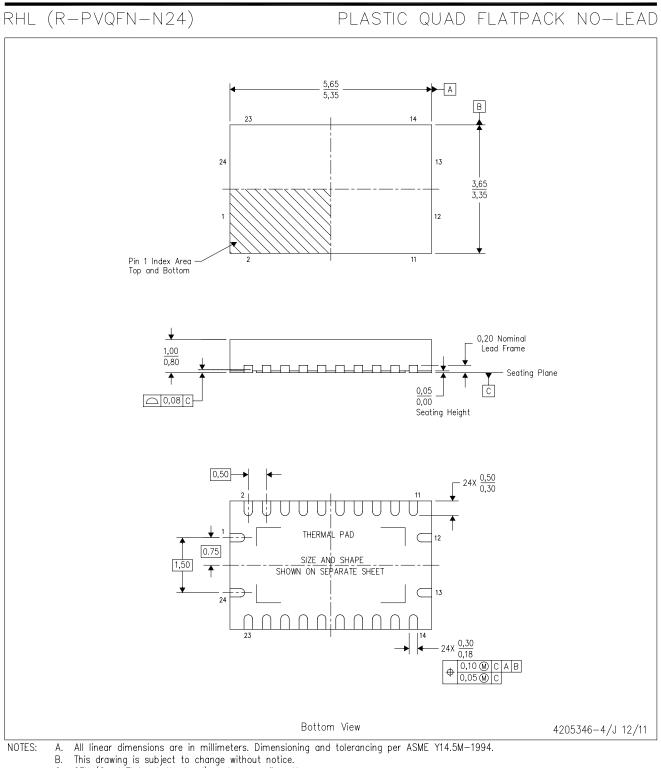


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

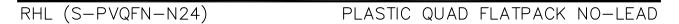


# **MECHANICAL DATA**



- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. JEDEC MO-241 package registration pending.



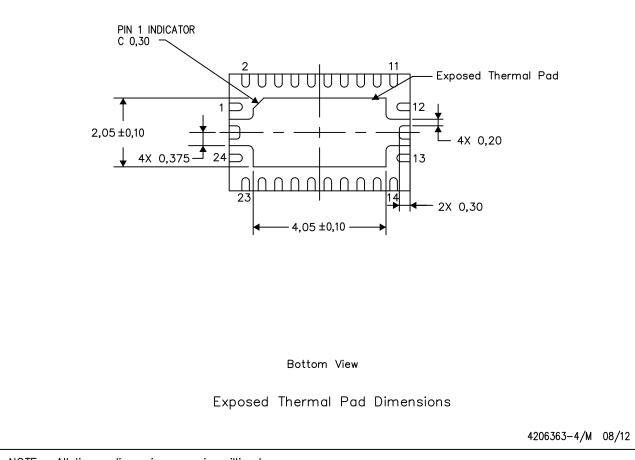


#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

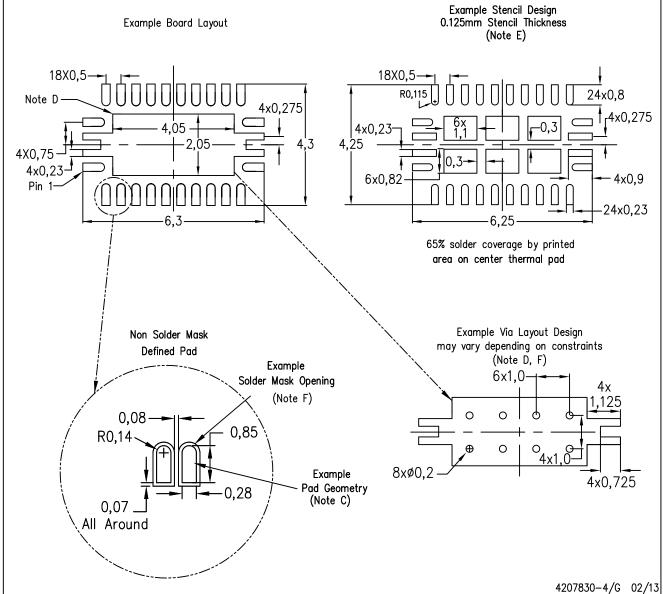
The exposed thermal pad dimensions for this package are shown in the following illustration.











NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.

D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.

- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



## MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0-10 Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

## DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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